# **Composite Electrode SnO<sub>2</sub>/TiO<sub>2</sub> for Dye-Sensitized Solar Cells**

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**Abstract:** Composite nanoporous electrode  $SnO_2/TiO_2$  was fabricated for the dye sensitized solar cell (DSSC) with N<sub>3</sub> (Cis-Ru). After introducing of TiO<sub>2</sub>, the open-circuit photovoltage (Voc) was higher than that of the pure  $SnO_2$  electrode, while short-circuit photocurrent (Isc) was varied with the ratio of the TiO<sub>2</sub>. Appropriate content of the TiO<sub>2</sub> can be beneficial to the efficiency of the solar cell, and it gives negative impact on the composite electrode when the content of TiO<sub>2</sub> is higher.

Keywords: Dye sensitized solar cell, SnO<sub>2</sub>/TiO<sub>2</sub> composite electrode, photoelectric conversion.

Much attention has been paid to improve the performance of the efficient photoelectronchemical cells, since Grätzel and his co-works reported a solar cell based on a ruthenium complex adsorbed on highly porous nanocrystalline  $\text{TiO}_2$  film<sup>1</sup>. Among them, the improvement of electrode is one of the important subjects, such as to search the alternative wide bandgap semiconductors<sup>2,3</sup>, to modify the TiO<sub>2</sub> by dopping or coating *et al.*<sup>4,5</sup> SnO<sub>2</sub> is one of the extensively studied wide bandgap semiconductors. However, its overall yield is not higher than 3%. In this letter, we report the synthesis of the composite SnO<sub>2</sub>/TiO<sub>2</sub> electrodes and their characteristics of the photo-electronic conversion.

### Experimental

Fluorine-doped SnO<sub>2</sub>-layerd glass plates  $(20\Omega/\Box)(SnO_2/F)$  were obtained from the Institute of Nonferrous Metals of China. Propylene carbonate (PC) was purchased from Acros. The redox electrode used in this work is 0.5 mol·L<sup>-1</sup> LiI + 0.05 mol·L<sup>-1</sup> I<sub>2</sub> + 0.1 mol·L<sup>-1</sup> *tert*-butylpyridine in a PC/MeCN (1:1, V/V) mixture solvent. Cis-Ru (N<sub>3</sub>) was synthesized according to the literature<sup>6</sup>.

Large size of nanocrystalline  $\text{SnO}_2$  colloid was prepared according to the procedure reported in the literature<sup>7</sup>, except that autoclaving was performing at 220°C for 30 h. After addition  $\text{SnO}_2$  powder (1g) to 80 mL different concentration of TiCl<sub>4</sub> aqueous solution, the mixture was sonicated for about half an hour. The mixture was refluxed at 90°C for 4 hours under continuous stirring and then allowed to cool overnight. Part of the precipitate, washed with deionized water several times, was used to perform XRD analysis. The DSSC cells were fabricated with 10 µm thick films and monitored with the

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method described in the literature<sup>8</sup>.

#### **Results and Discussion**

It can be seen from **Figure 1** that no pure  $TiO_2$  rutile phase appears when the concentration of  $TiCl_4$  is 0.01 mol·L<sup>-1</sup> or lower. With the  $Ti^{4+}$  content increasing to 0.05 mol·L<sup>-1</sup>, a rutile phase of  $TiO_2$  can be detected in composite electrode (in **Figure 1** curve e). It can be inferred from the results of XRD that when  $Ti^{4+}$  ion content is very low,  $Ti^{4+}$  ion should be adsorbed on to the surface of  $SnO_2$  particles, and the rutile phase is formed when the concentration gets higher.

Figure 1 XRD pattern of SnO<sub>2</sub> and SnO<sub>2</sub>/TiO<sub>2</sub> powder product.



(a) SnO<sub>2</sub>, (b) SnO<sub>2</sub>/0.0015 mol TiCl<sub>4</sub>, (c) SnO<sub>2</sub>/0.0045 mol TiCl<sub>4</sub>, (d) SnO<sub>2</sub>/0.01 mol TiCl<sub>4</sub> and (e) SnO<sub>2</sub>/0.05 mol TiCl<sub>4</sub>

**Table 1** surmarized some parameters obtained from a thin-layer sandwich-type solar cell under illumination of white light from Xe lamp (67.2 mW·cm<sup>-2</sup>) and the effective illumination area is 0.182 cm<sup>2</sup>. We can see in **Table 1** that open-circuit photovoltage (Voc) and the fill factor (FF) of the solar cells fabricated by composite electrodes are higher than those of pure SnO<sub>2</sub>. At an appropriate content Ti<sup>4+</sup> coated SnO<sub>2</sub>, although the sample d cell gave a shot-circuit photocurrent (Isc) of 13.5 mA·cm<sup>-2</sup>, which is lower than that of pure SnO<sub>2</sub>, it got a much higher open-circuit photovoltage (Voc) of 492 mV and a better fill factor (FF) of 0.44. Therefore, higher Voc and FF of the composite electrode offset the decrease of Isc and result in the overall yield ( $\eta$ ) 4.33 %, which is superior to the efficiency of pure SnO<sub>2</sub> cell.

electrode	molar ratio of Ti:Sn	dye molar/cm <sup>2</sup>	η(%)	Voc(mV)	Isc(mA)	FF
SnO <sub>2</sub>	/	0.76×10 <sup>-7</sup>	2.31	299	16.3	0.32
SnO <sub>2</sub> /0.0015 mol TiCl <sub>4</sub>	1:70.2	1.15×10 <sup>-7</sup>	2.82	352	17.5	0.31
SnO <sub>2</sub> /0.0045 mol TiCl <sub>4</sub>	1:23.	1.06×10 <sup>-7</sup>	2.81	388	14.3	0.34
SnO <sub>2</sub> /0.01 mol TiCl <sub>4</sub>	1:10.5	1.65×10 <sup>-7</sup>	4.33	492	13.5	0.44
SnO <sub>2</sub> /0.05 mol TiCl <sub>4</sub>	1:2.1	1.24×10 <sup>-7</sup>	0.84	489	1.9	0.59

 Table 1
 Electrode characteristics and parameters for their DSSCs

Figure 2 Dark current of the bare  $SnO_2$  electrode and the composite  $SnO_2/TiO_2$  electrodes.



Scan rate is 10 mV/s, and the electrolyte is 0.5 mol·L<sup>-1</sup> LiI, 0.05 mol·L<sup>-1</sup> I<sub>2</sub>, 0.1 mol·L<sup>-1</sup> 4-*tert*-butylpyridine in 1:1 acetonitrile-propylene carbonate.

Figure 2 shows the dark current of the electrodes. Data show that the dark current of all composite electrodes is lower than that of the bare SnO<sub>2</sub> electrode under the same bias voltage used, and that the more concentration of the  $Ti^{4+}$ , the lower the dark current gets. This phenomenon indicates that electron recombination rate decreases, which might attribute to the energy barrier formed after  $TiO_2$  coating. The coating layer  $TiO_2$  serves as the energy barrier between the excited cis Ru(II) and  $SnO_2$  layer. When the ratio of Ti:Sn is small, the electrons transport from Ru(II)\* to TiO<sub>2</sub>, and then inject into SnO<sub>2</sub>. In this situation, the  $SnO_2$  is close to the CTO substrate, therefore, the injected electrons easily reach to the substrate. Such scene can be illuminated in the Scheme 1. With the ratio Ti:Sn is increasing greatly, the  $SnO_2$  particles might disperse around TiO<sub>2</sub> particles. In this case, these injected electrons in the  $TiO_2$  cannot reach to the substrate but transfer to the electron collector tank, SnO<sub>2</sub> nanoparticles. Then these SnO<sub>2</sub> nanoparticles serve as trap centers to annihilate injected electron. It is unfavorable for these trapped electrons to reach the CTO substrate with 0.3 V energy difference between the rutile  $TiO_2$  and  $SnO_2$ In this circumstance, such structure does not favor electron transfer. particles. Therefore appropriate content  $TiO_2$  layer plays an important role in decreasing electron

recombination rate and the optimized  $SnO_2/TiO_2$  composite electrode to give better performance than that of pure  $SnO_2$ .

Scheme 1 The electron transfer way when the TiO2 coating layer is thin.



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